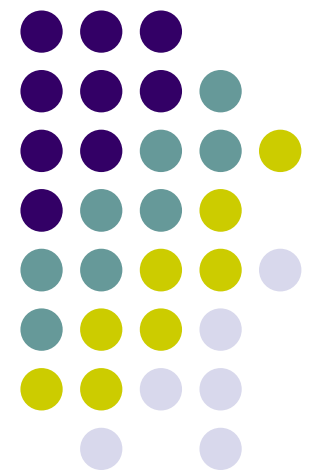
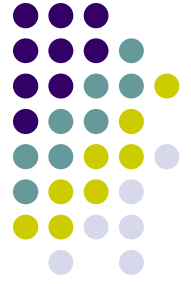


Solar cells

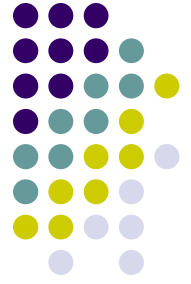


Overview



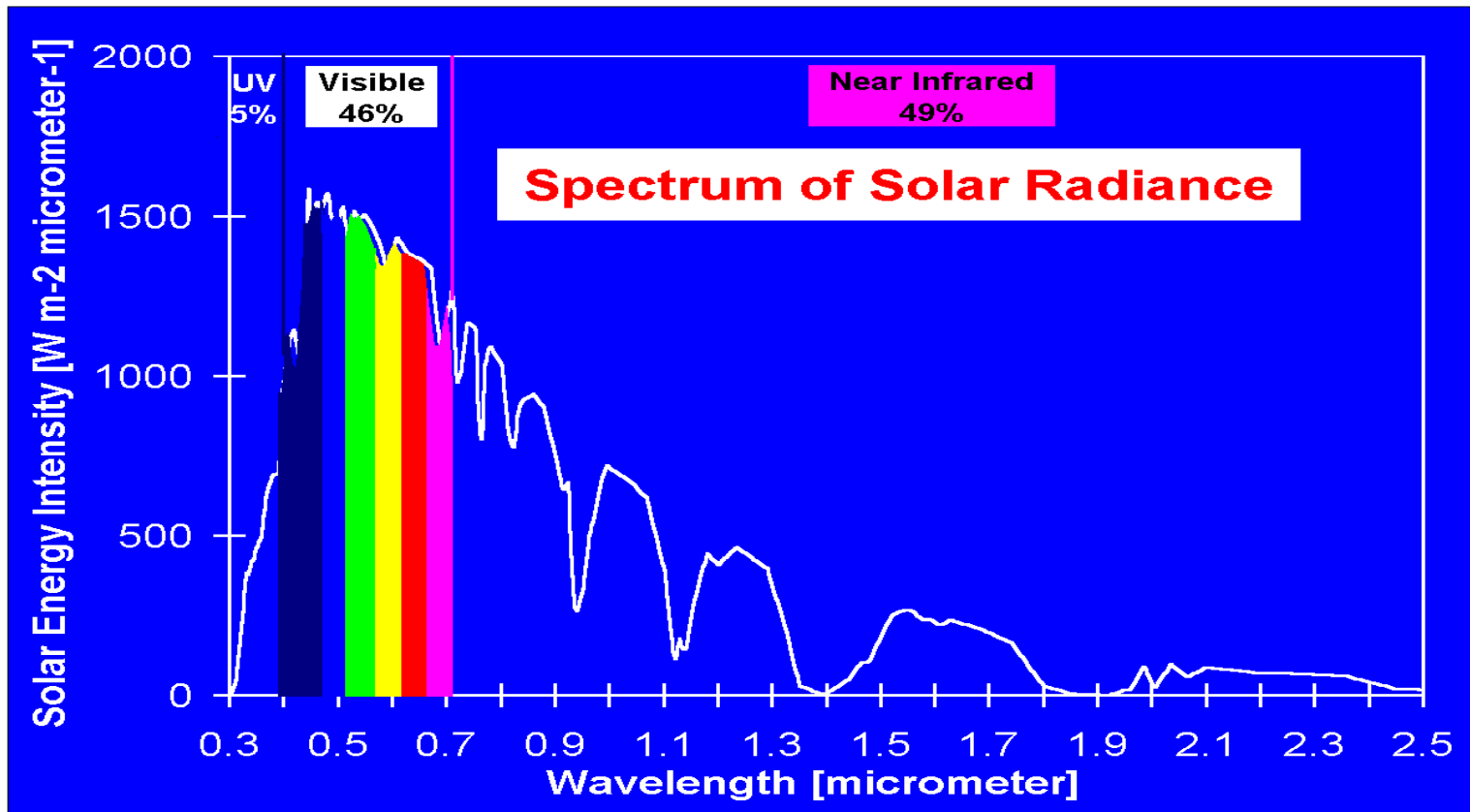
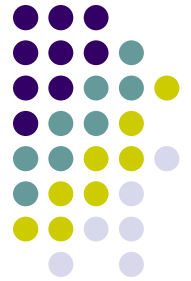
- Solar cell fundamentals
- Novel solar cell structures
- Thin film solar cells
- Next generation solar cell

Appealing Characteristics



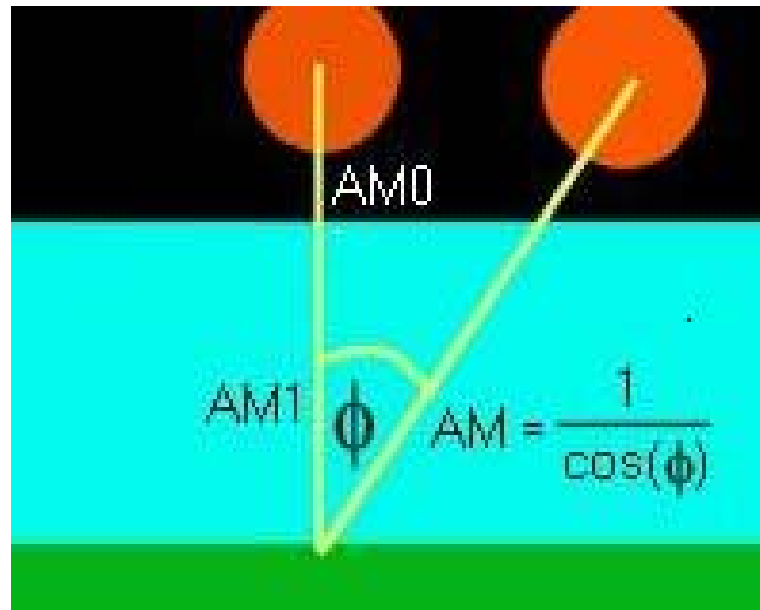
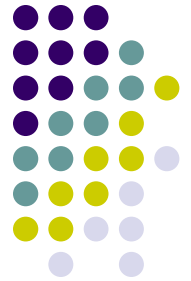
- Consumes no fuel
- No pollution
- Wide power-handling capabilities
- High power-to-weight ratio

Solar Energy Spectrum



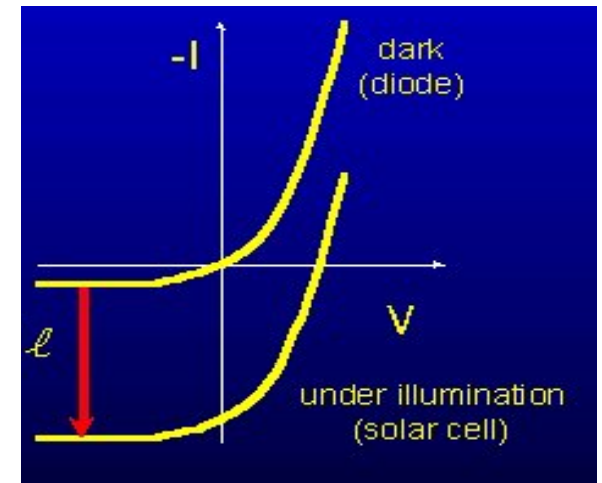
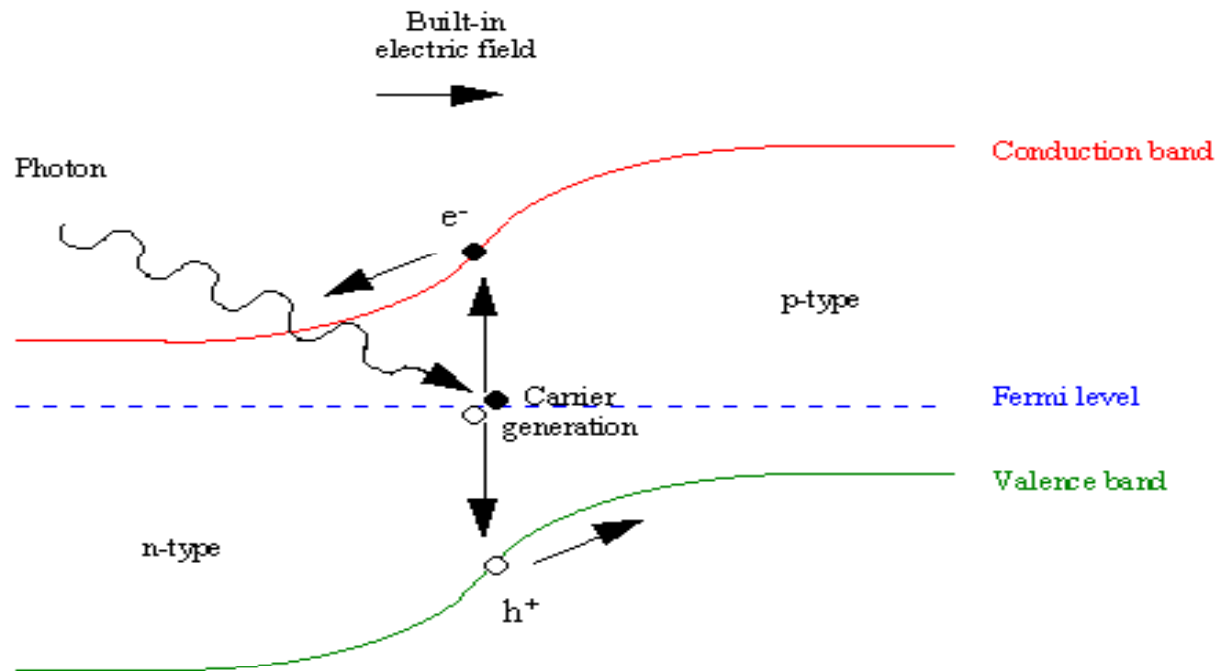
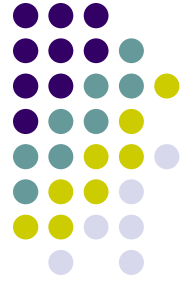
- Power reaching earth 1.37 KW/m²

Air Mass



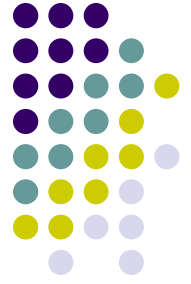
- Amount of air mass through which light pass
- Atmosphere can cut solar energy reaching earth by 50% and more

Solar cell – Working Principle



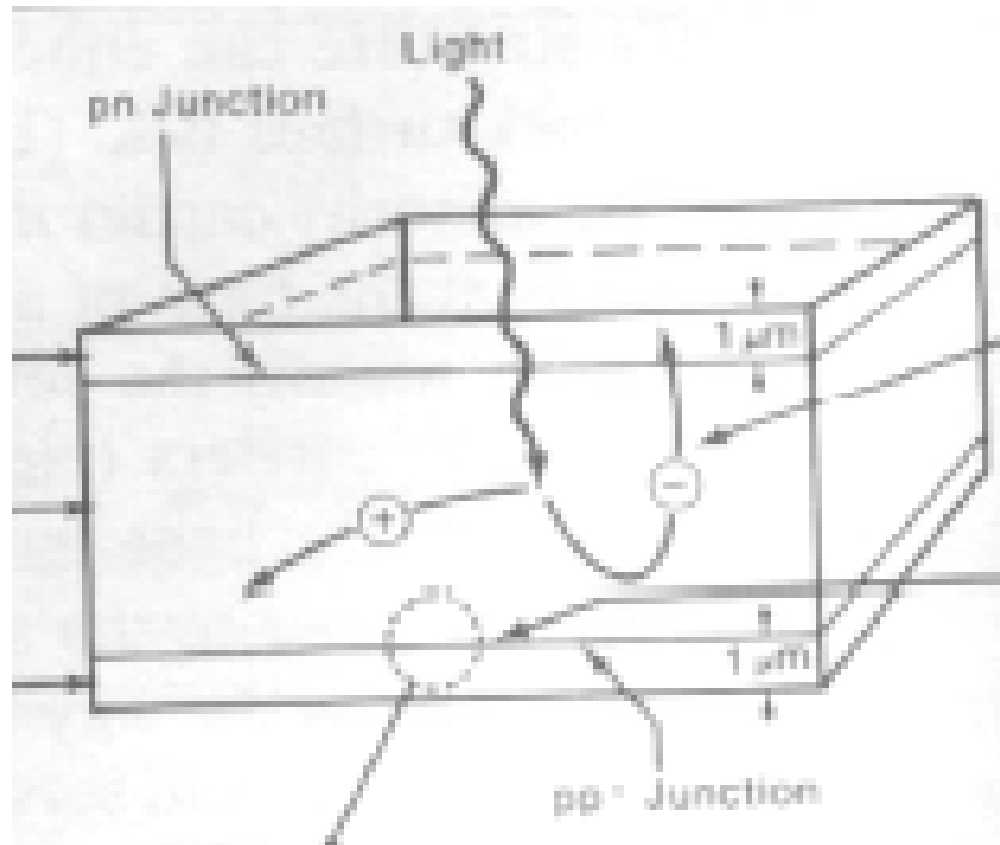
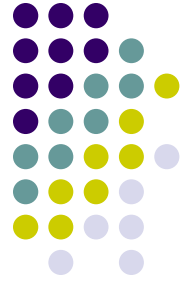
- Operating diode in fourth quadrant generates power

Overview



- Solar cell fundamentals
- **Novel solar cell structures**
- Thin film solar cells
- Next generation solar cell

Back Surface Fields



- Most carriers are generated in thicker p region
- Electrons are repelled by p-p⁺ junction field



Schottky Barrier Cell

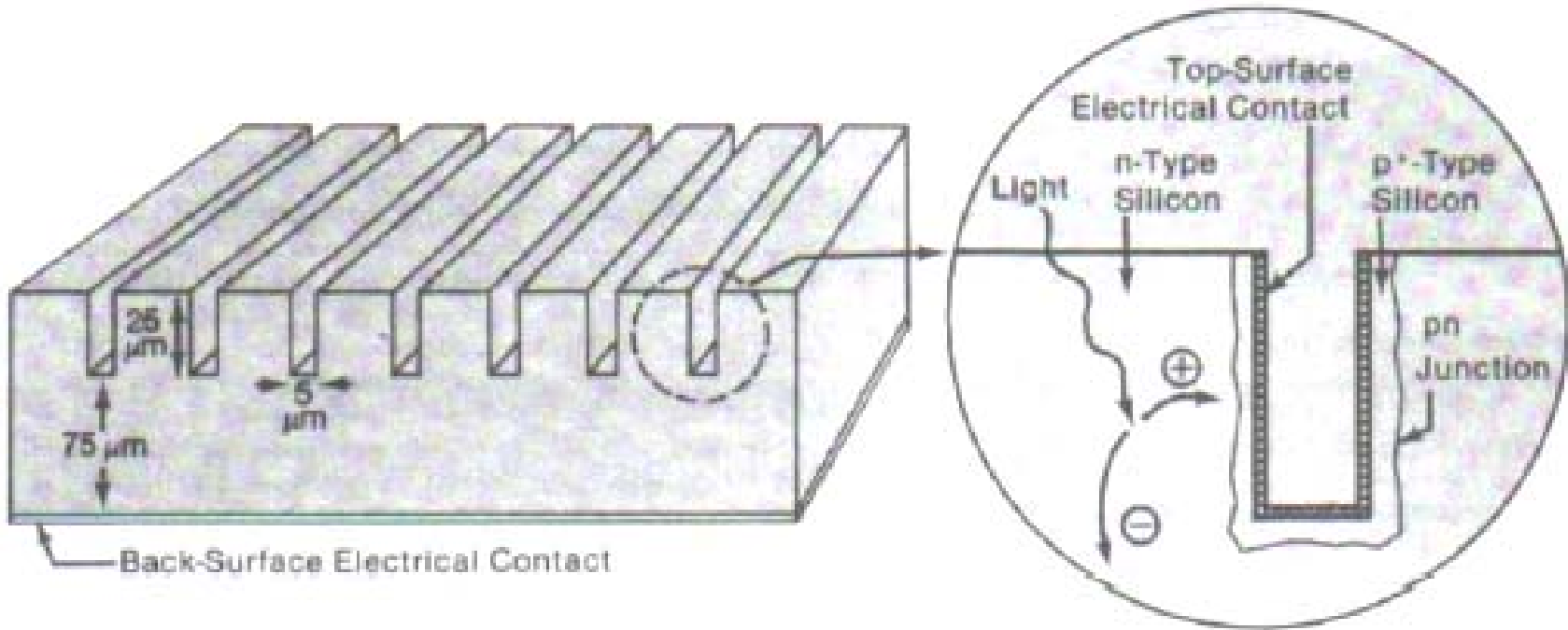
- Principle similar to p-n junction cell
- Cheap and easy alternative to traditional cell

Limitations:

- Conducting grid on top of metal layer
- Surface damage due to high temperature in grid-attachment technique

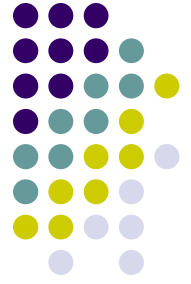


Grooved Junction Cell



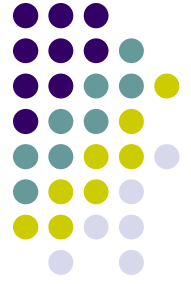
- Higher p-n junction area
- High efficiency ($> 20\%$)

Overview



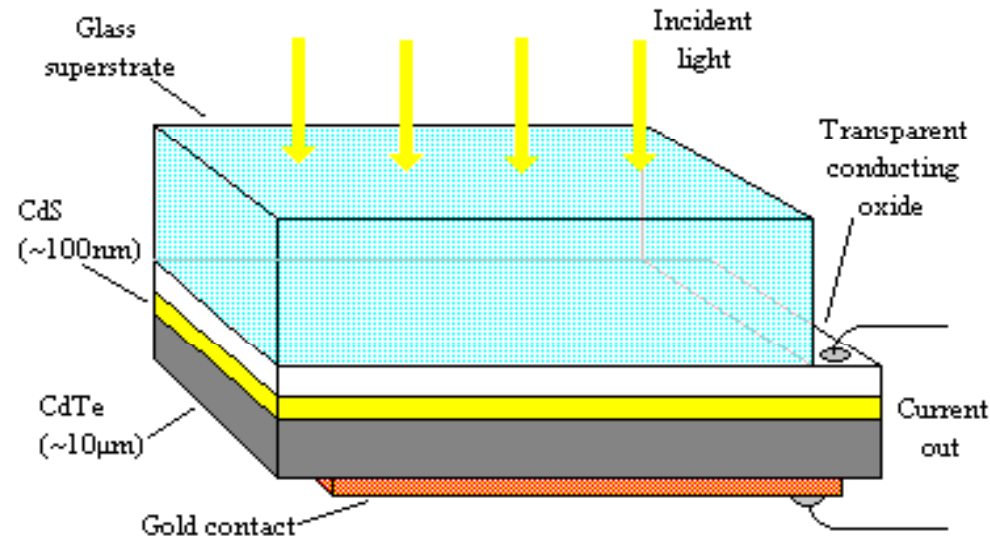
- Solar cell fundamentals
- Novel solar cell structures
- **Thin film solar cells**
- Next generation solar cell

Thin Film Solar Cells



- Produced from cheaper polycrystalline materials and glass
- High optical absorption coefficients
- Bandgap suited to solar spectrum

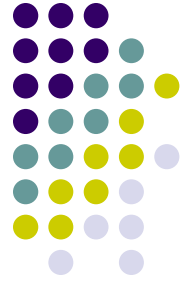
CdTe/CdS Solar Cell



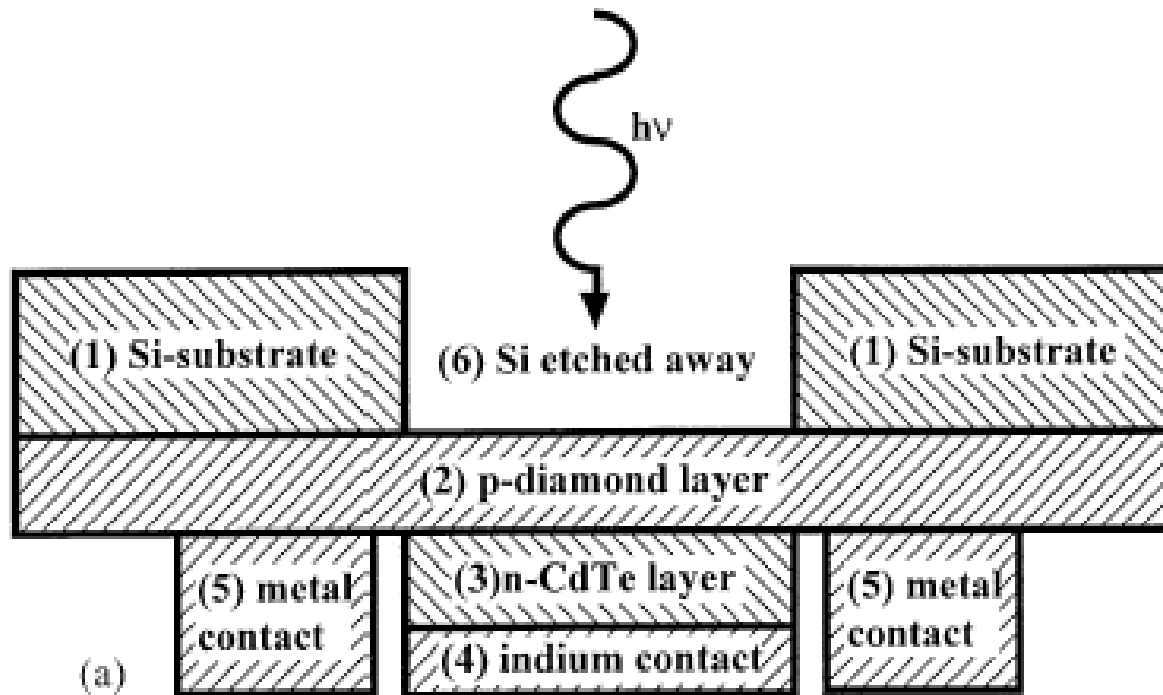
- **CdTe** : Bandgap 1.5 eV; Absorption coefficient 10 times that of Si
- **CdS** : Bandgap 2.5 eV; Acts as window layer

Limitation :

Poor contact quality with p-CdTe ($\sim 0.1 \Omega\text{cm}^2$)

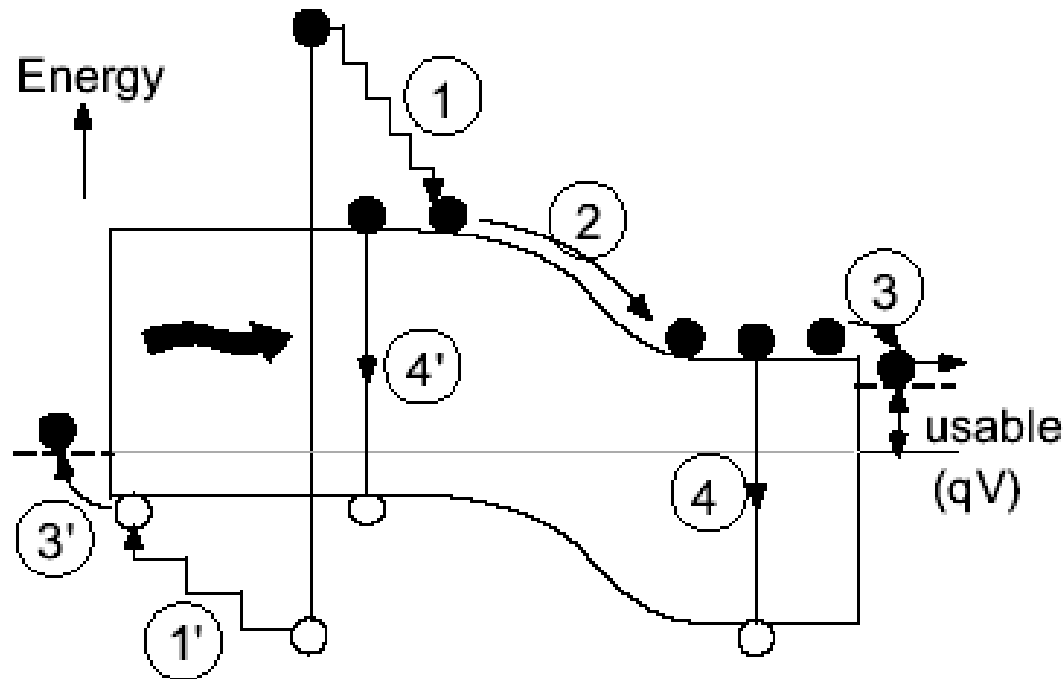
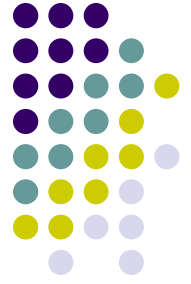


Inverted Thin Film Cell



- p-diamond (Bandgap 5.5 eV) as a window layer
- n-CdTe layer as an absorption layer

Efficiency Losses in Solar Cell

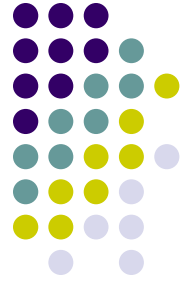


1 = Thermalization loss

2 and 3 = Junction and contact voltage loss

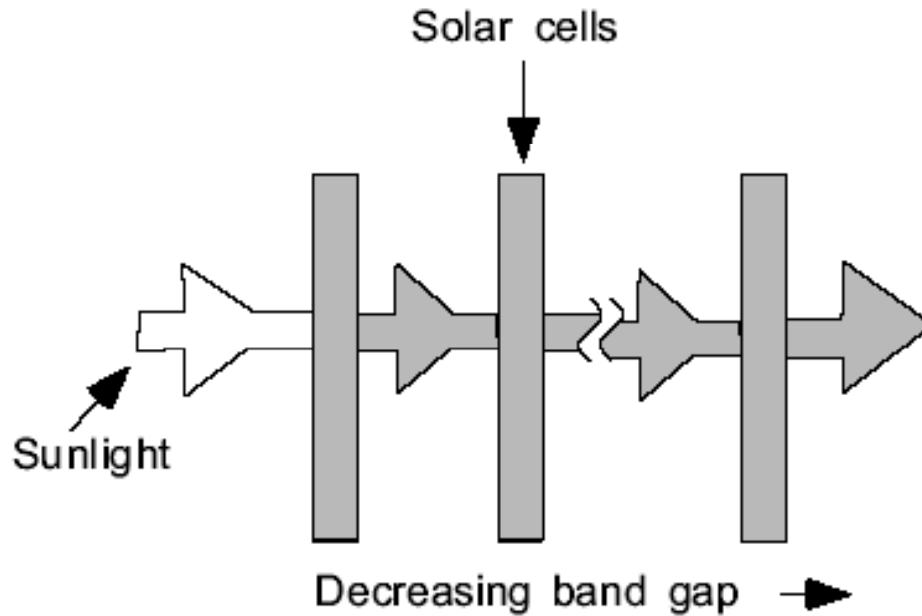
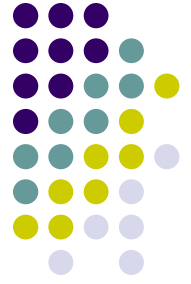
4 = Recombination loss

Overview



- Solar cell fundamentals
- Novel solar cell structures
- Thin film solar cells
- Next generation solar cell

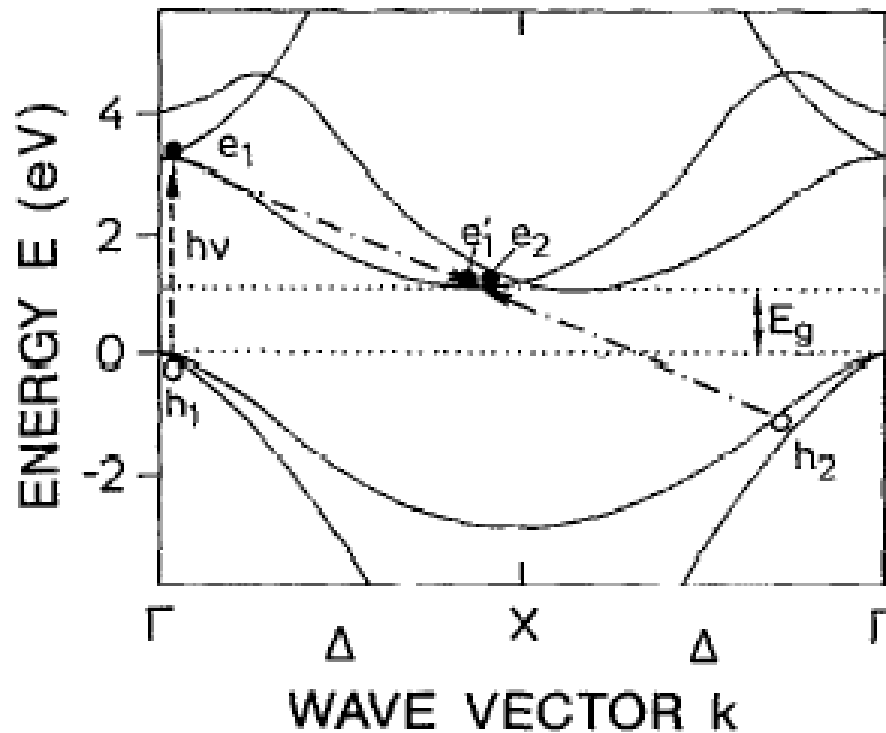
Tandem Cells



- Current output matched for individual cells
- Ideal efficiency for infinite stack is 86.8%
- GaInP/GaAs/Ge tandem cells (efficiency 40%)

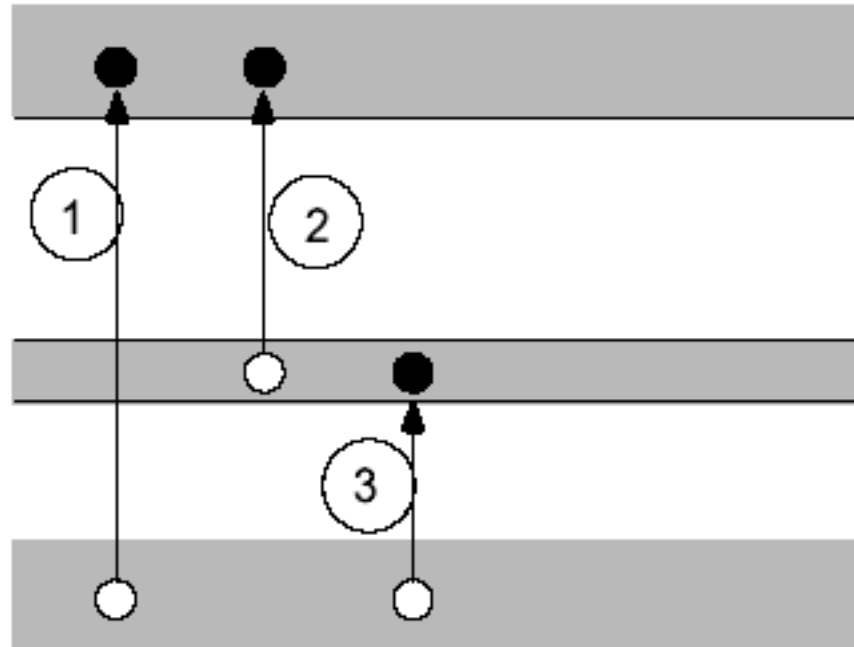
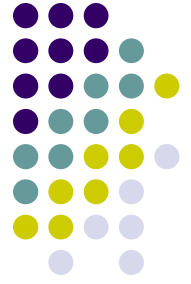


Multiple E-H pairs



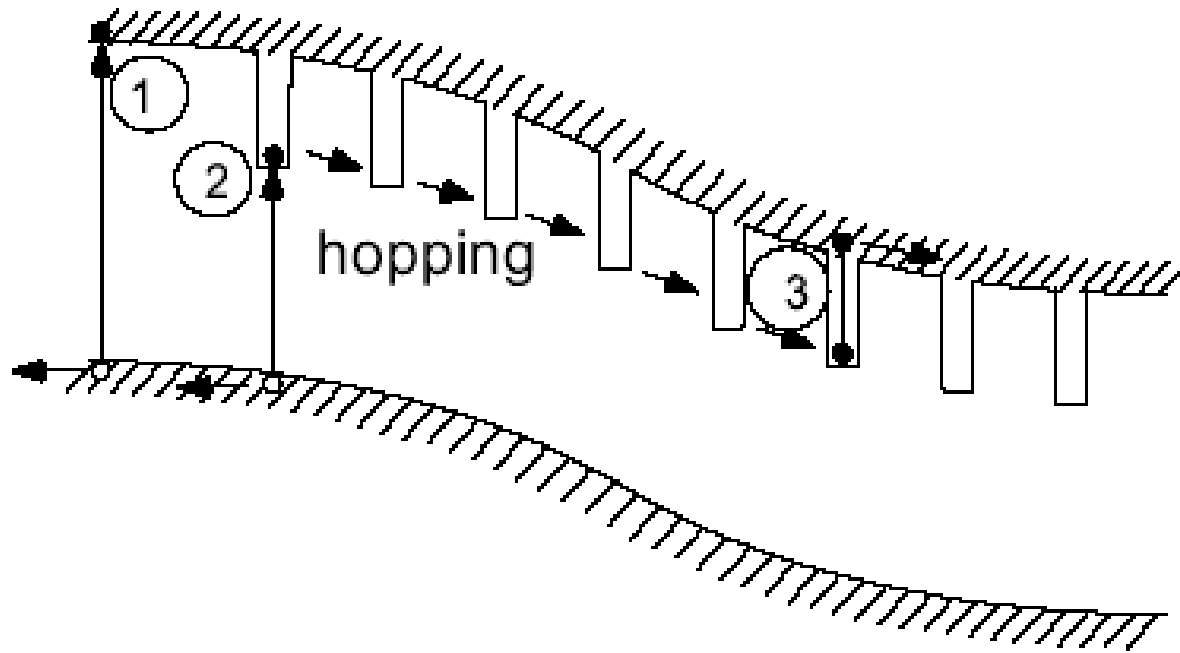
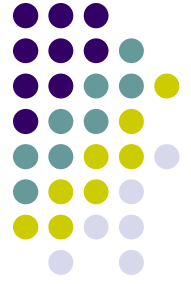
- Many E-H pairs created by incident photon through impact ionization of hot carriers
- Theoretical efficiency is 85.9%

Multiband Cells

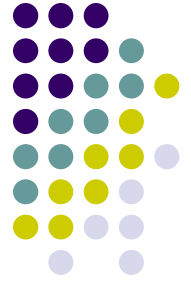


- Intermediate band formed by impurity levels.
- Process 3 also assisted by phonons
- Limiting efficiency is 86.8%

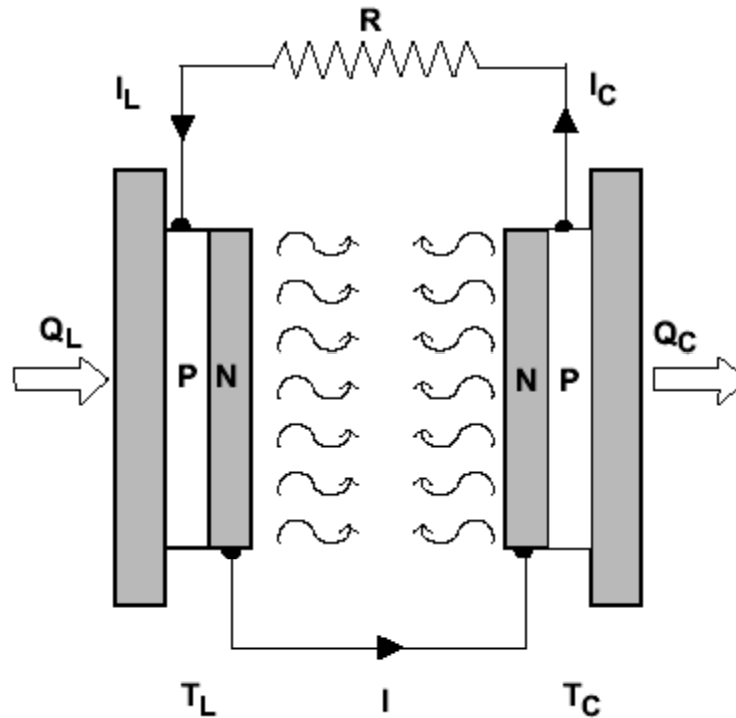
Multiple Quantum Well



- Principle of operation similar to multiband cells

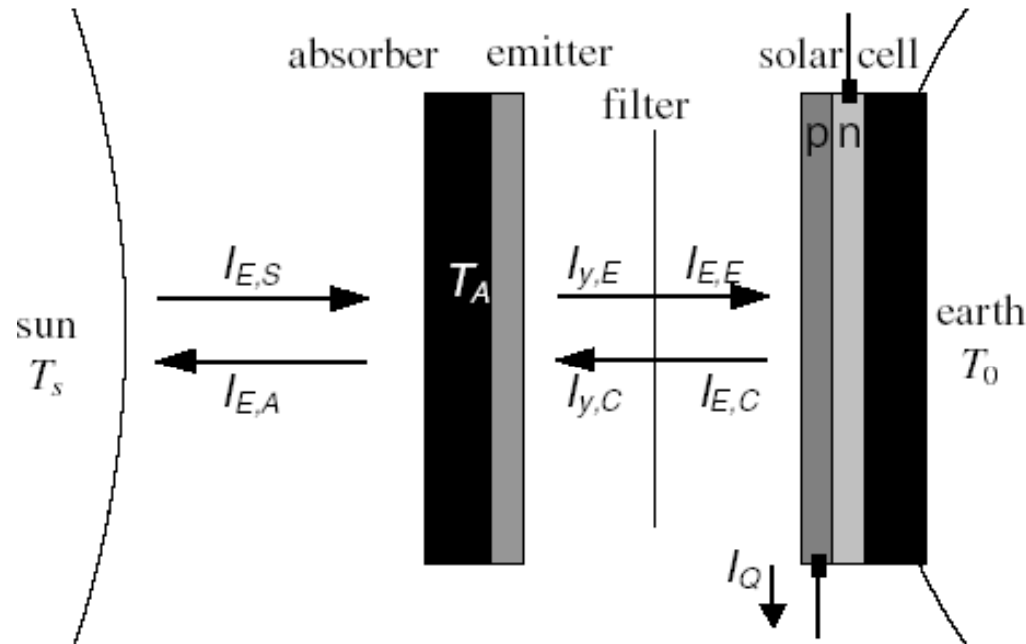
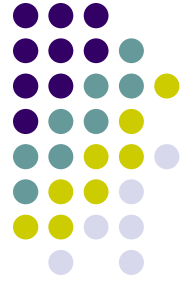


Thermophotonic Cells



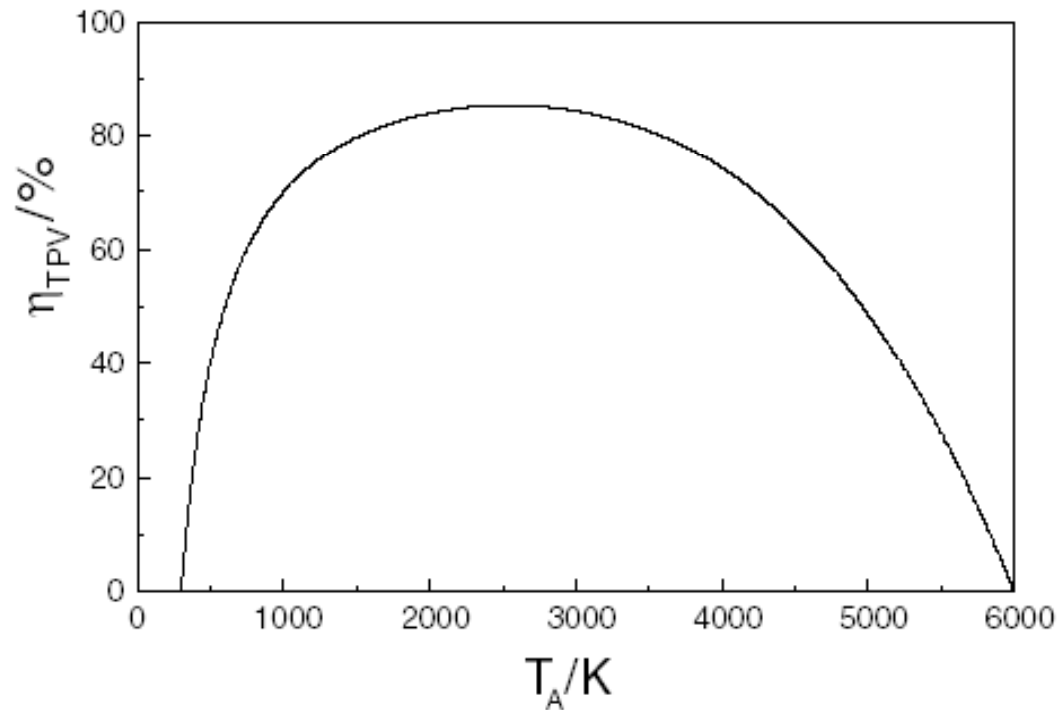
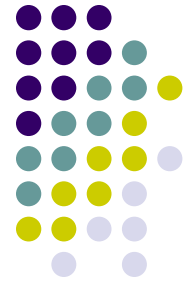
- Heated semiconductor emits narrow bandwidth radiations
- Diode with higher temperature has lower voltage

Thermophotovoltaic Cell



- Filter passes radiations of energy equal to bandgap of solar cell material
- Emitter radiation matched with spectral sensitivity of cell
- High Illumination Intensity ($\sim 10 \text{ kW/m}^2$)

Thermophotovoltaic Cells



$$\eta_{TPV} = \left(1 - \frac{\pi T_A^4}{\Omega_S T_S^4}\right) \left(1 - \frac{T_0}{T_A}\right)$$

- Efficiency almost twice of ordinary photocell